

#### **ESD Protection Diode**

DOC.NO.: ISS-CLAMP1211P

# INDIVIDUAL SPECIFICATION SHEET

Product Name: ESD Protection Diode

Part Number: CLAMP1211P

**Revision:** A







### Dongguan TLC Electronic Technology Co., LTD

No.18,5th GaoLi Road, TangXia Town, DongGuan, GuangDong, P.R China 523710

TEL: 86-0769-3892 0511
FAX: 86-0769-8793 2077
Http: www.tlcet.com.cn

Rev.	Effective Date	Changed Contents
Α	2021-10-20	New Release

The individual specification sheet are the property of Dongguan TLC electronic technology Co.,Ltd and shall not be copied or used as commercial purposes without permission.

PREPEARED BY	APPROVED BY
杨崎	A BOB



### CLAMP1211P

#### Low-Capacitance Bidirectional Micro Packaged TVS Diodes for ESD Protection

The CLAMP1211P is designed with Jksemi Punch-Through process TVS technology to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time provide best in class protection on designs that are exposed to ESD. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space comes at a premium. Also because of its low capacitance, it is suited for use in high frequency designs such as USB 2.0 high speed, VGA, DVI, SDI and other high speed line applications.

It has been specifically designed to protect sensitive components which are connected to data and transmission lines from overvoltage caused by ESD(electrostatic discharge), and EFT (electrical fast transients).

#### **Features**

- ♦ Peak Power Dissipation –250 W (8 x 20 us Waveform)
- ♦ Stand-off Voltage: 12 V
- ♦ Low capacitance (<35.0pF) for high-speed interfaces
- ♦ Replacement for MLV (0402)
- ♦ Protects I/O Port
- ♦ Low Clamping Voltage
- ♦ Low Leakage
- ♦ Low Capacitance
- $\Leftrightarrow$  Response Time is < 1 ns
- ♦ Meets MSL 1 Requirements
- ♦ ROHS compliant
- ♦ Solid-state Punch-Through TVS Process technology
- ♦ WeiPan technology

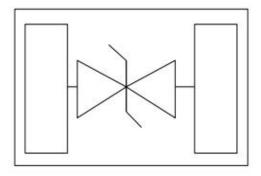
### Main applications

- ♦ Serial and Parallel Ports
- ♦ Notebooks, Desktops, Servers
- ♦ Projection TV
- ♦ Cellular handsets and accessories
- ♦ Portable instrumentation
- ♦ Peripherals
- ♦ MP3 Players

#### Protection solution to meet

- ♦ IEC61000-4-2 (ESD) ±15kV (air), ±8kV (contact)
- IEC61000-4-5 (Lightning) 10A (8/20μs)





#### **Ordering Information**

Device	Qty per Reel	Reel Size		
CLAMP1211P	5000/10000	7 Inch		



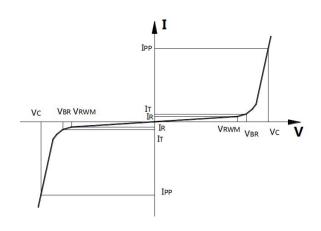
Maximum ratings (Tamb=25℃ Unless Otherwise Specified)						
Parameter	Symbol	Value	Unit			
Peak Pulse Power (tp=8/20μs waveform)	Рррр	250	Watts			
ESD Rating per IEC61000-4-2: Contact		8	KV			
Air	15 K					
Lead Soldering Temperature	TL	260 (10 sec.)	$^{\circ}$			
Operating Temperature Range	Tı	<b>-</b> 55 ∼ 150	$^{\circ}$			
Storage Temperature Range	Tstg	<b>-</b> 55 ∼ 150	$^{\circ}$			
Lead Solder Temperature – Maximum (10 Second Duration)	TL	260	$^{\circ}$			

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

Junction capacitance is measured in VR=0V,F=1MHz

Electrical characteristics ( Tamb=25°C Unless Otherwise Specified)								
Symbol	Parameter	Parameter Conditions Min. Typ.		Max.	Units			
$V_{RWM}$	Reverse Working Voltage				12	V		
$V_{BR}$	Reverse Breakdown Voltage	IT = 1mA	13.3			V		
$I_R$	Reverse Leakage Current	$V_{RWM} = 12V$		0.01	0.2	μΑ		
V	Clamping Voltage	$I_{PP} = 1A$ , $tp = 8/20 \mu s$		15	19	V		
$V_{\rm C}$		$I_{PP} = 10A, tp = 8/20 \mu s$		21	25	V		
C <sub>J</sub>	Junction Capacitance	$V_R = 0V, f = 1MHz$			35	pF		

Symbol	Parameter		
Vrwm	Working Peak Reverse Voltage		
VBR	Breakdown Voltage @ IT		
V <sub>C</sub>	Clamping Voltage @ IPP		
$I_{T}$	Test Current		
Irm	Leakage current at VRWM		
Ірр	Peak pulse current		
Co	Off-state Capacitance		
C <sub>J</sub>	Junction Capacitance		

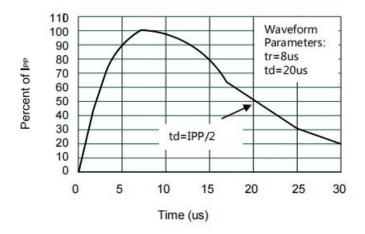


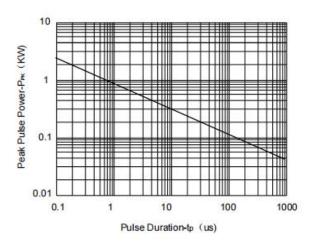
<sup>\*</sup>Other voltages may be available upon request.

<sup>1.</sup> Non-repetitive current pulse, per Figure 1.



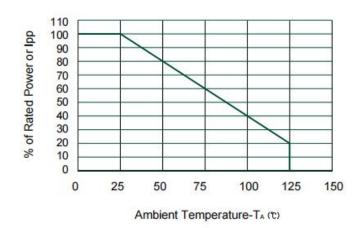
### **Typical electrical characterist applications**





Pulse Waveform

Non-Repetitive Peak Pulse Power vs. Pulse Time



Power Derating Curve



### **DFN-1006**

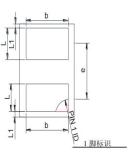
## **Package Information**

#### **Mechanical Data**

Case:DFN1006

Case Material: Molded Plastic. UL Flammability

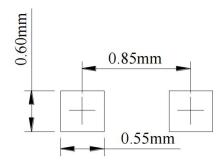




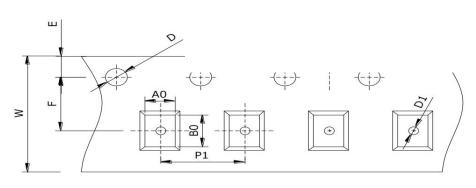


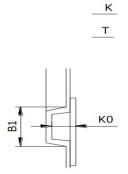
DIM	Millimeters		Inches		
	Min	Max	Min	Max	
A	0.30	0.50	0.012	0.020	
A1	0.00	0.05	0.000	0.002	
D	0.55	0.65	0.022	0.026	
E	0.95	1.05	0.037	0.041	
b	0.25	0.60	0.010	0.024	
e	0.65TYP		0.026TYP		
L	0.15	0.35	0.006	0.014	
L1	0.05REF		0.002REF		

## **Recommended Pad outline**



### **DFN1006 Reel Dim**





Package	Chip Size (mm)	Pocket Size B0×A0×K0(mm)	Tape Width	Reel Diameter	Quantity Per Reel	P0	P1
DFN1006	1.0×0.6×0.50	1.10×0.70×0.60	8mm	178mm(7")	5000/10000	4mm	4/2mm
D0	D1	E	F	K	Т	W	
1.5mm	0.5mm	1.75mm	3.5mm	0.55mm	0.2mm	8mm	